NSN 5961-01-299-9818

Transistor - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

0.210 inches

Terminal Length:

0.500 inches

Overall Diameter:

0.230 inches

End Application:

Rt-1168b

Internal Configuration:

Field effect-dual gate

Electrode Internally-electrically Connected To Case:

Source

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

30.0 drain to gate voltage and 25.0 drain to source voltage

Current Rating Per Characteristic:

50.00 amperes source cutoff current of standard range

Power Rating Per Characteristic:

1.2 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

Test Data Document:

37695-615238 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

4 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0